

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LV8019LP — Forward/Reverse Motor Driver

Overview

The LV8019LP is a forward/reverse motor driver.

Features

- One H-bridge driver channel
- Provides a constant current output
- Built-in thermal shutdown circuit

Specifications

Maximum Ratings at Ta = 25°C and SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Output block supply voltage	VM max		-0.5 to 8.4	V
Control block supply voltage	V _{CC} max		-0.5 to 7.0	V
Constant current output block supply voltage	VRG max		-0.5 to 6.0	V
Maximum output current	I _O max		1.2	Α
	I _O peak1	t ≤ 200ms, f = 2Hz	3	Α
	I _O peak2	t ≤ 10ms, f = 2Hz	5	Α
Input signal voltage	V _{IN} max		-0.5 to V _{CC} +0.5	Α
Allowable power dissipation	Pd max1	Independent IC	0.2	W
	Pd max2	When mounted on a circuit board *1	1.05	W
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

 $^{^{\}star}$: Specified substrate : 40×50×0.8mm³, glass epoxy four-layer (2S2P) board

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LV8019LP

Recommended Operating Conditions at Ta = 25°C and SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Output block supply voltage	VM		3.0 to 7.4	V
Control block supply voltage	V _{CC}		2.7 to 6.0	V
Constant current output block supply voltage	VRGIN		1.5 to V _{CC}	V
Input signal voltage	V _{IN}		0 to V _{CC}	V
Maximum input signal frequency	f _{max}	Duty = 50%	100	kHz

Electrical Characteristics Ta = 25°C, $V_{CC} = VM = 5V$, and SGND = PGND = 0V unless otherwise specified.

Parameter		Cumple of	Symbol Conditions		Ratings			
Farameter		Symbol		min	typ	max	Unit	
Standby mode output block		IMO	EN = 0V, IN1 = IN2 = ICTRL = 0V			1.0	μΑ	
Control block current				0	1.0	μА		
consumption	Operation mode	Icc	EN = 5V		0.8	1.3	mA	
High-level input vol	High-level input voltage		IN*	2.5		Vcc	V	
Low-level input volt	age	V _{IN} ∟	IN*	0		0.8	V	
High-level input cur	rent	I _{IN} H	IN*			1.0	μА	
Low-level input curi	rent	I _{IN} L	IN*	-1.0			μА	
High-level EN pin c	High-level EN pin current		EN	15	25	35	μА	
Low-level EN pin cu	Low-level EN pin current		EN			1.0	μА	
Output on	Output on 1		VM = 5V, sink + source		0.30	0.40	Ω	
resistance 2 R		R _{ON} 2	VM = 3V, sink + source		0.45	0.60	Ω	
ISET setting resista	ISET setting resistance		Between ISET pin and SGND	80			Ω	
ISET pin voltage		VISET	RSET > 80Ω	0.90	1.05	1.20	V	
CC pin output saturation voltage		VCSAT	RSET = 150Ω *1			1.5	V	
CC pin output leaka	age current	ICONL	CTRL = 0V			1.0	μА	
Low voltage shutdown operation voltage		VLVD	V _{CC} pin voltage detection	2.10	2.35	2.60	V	
High-level output turn-on time		ТОН	The transition from 10% to 90% of the output amplitude *2		0.1	1.0	μs	
Low-level output turn-on time		TOL	The transition from 90% to 10% of the output amplitude *2		0.2	2.0	μS	
Thermal shutdown temperature		TSD	*2	150	180		°C	
Thermal shutdown hysteresis		ΔTSD	*2		40		°C	

^{*1 :} Voltage between CC pin and ISET pin

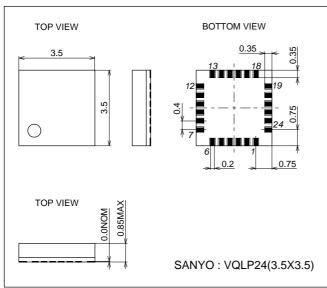
 $[\]ensuremath{^{\star}2}$: Design guarantee: These characteristics are not measured.

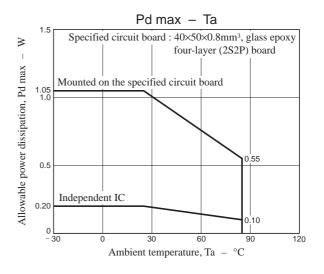
LV8019LP

Package Dimensions

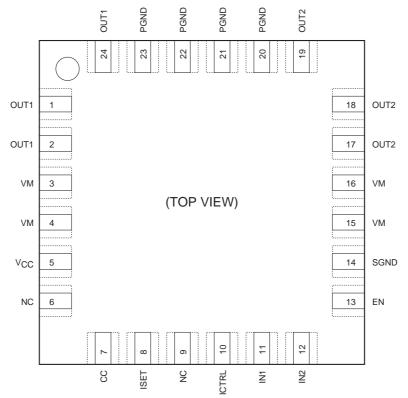
unit: mm (typ)

3321

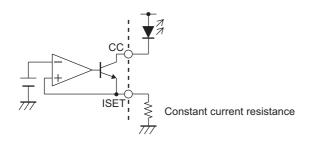




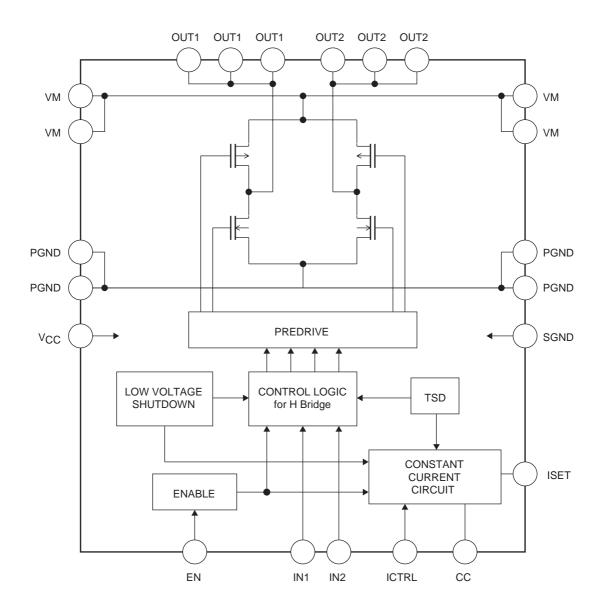
Pin Assignment



Constant current output



Block Diagram



Truth Table

EN	IN1	IN2	CTRL	OUT1	OUT2	СС	Mode	
Н	Н	Н	X	L	L	Х	Break	
Н	Н	L	X	Н	L	Х	Forward	
Н	L	Н	Х	L	Н	Х	Reverse	
Н	L	L	X	Z	Z	X	Standby	
L	Х	X	Х	L	L	L	Standby	
Н	Х	Х	L	Х	Х	Z	Constant current output off	
Н	Х	Х	Н	Х	Х	ON	Constant current output on	

H : High level

L : Low level

Z : Hi-impedance

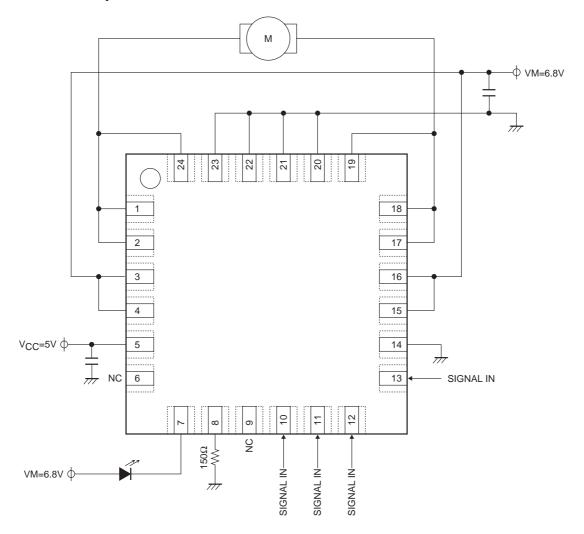
X : Don't care

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Pin Functions

Pin Func	lions		
Pin No.	Pin	Description	Equivalent circuit
11 12	IN1 IN2	Logic input 1 Logic input 2 The output is set by the combination of the input 1 and 2 states. See the truth table for details. Controls the output on/off state of the constant current block.	V_{CC} $IN1$ $IN2$ $ICTRL$ S-GND
13	EN	EN pin Controls the on/off state of the H-bridge output (OUT1 and OUT2) and the constant current output. See the truth table for details.	VCC $10k\Omega$ $10k\Omega$ $200k\Omega$ S-GND
1, 2, 24, 17, 18, 19	OUT1 OUT2	Output 1 Output 2 The source side is a p-channel transistor and sink side is an n-channel transistor.	VM OUT*
7 8	CC ISET	Constant current output Constant current setting The output current (CC) is set by connecting a resistor between the ISET pin and ground.	VCC CC SGND SGND SGND SGND
5	Vcc	Signal system power supply	Vcc
3, 4, 15, 16	VM	Power system power supply	VM ()———
14	SGND	Signal system ground	SGND (
21, 22, 23	PGND	Power system ground	PGND —

Application Example



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